

AMENDMENT

In the Claims

This listing of claims replaces all prior versions, and listings, of claims in the application:

1. (Currently Amended) An electroluminescent display device, comprising:
a plurality of pixels;
an electroluminescent element provided in each of the pixels;
a pixel selecting transistor provided in each of the pixels and selecting ~~[[the]]~~ a
corresponding pixel in response to a gate signal; and
a driving transistor provided in each of the pixels and supplying an electric current to
~~[[the]]~~ a corresponding electroluminescent element in response to a display signal supplied
through the corresponding pixel selecting transistor,
wherein the pixel selecting transistor comprises an active layer made of polysilicon, and
the driving transistor comprises an active layer made of amorphous silicon.
2. (Currently Amended) An electroluminescent display device, comprising:
a plurality of pixels;
an electroluminescent element provided in each of the pixels;
a pixel selecting thin film transistor provided in each of the pixels and selecting ~~[[the]]~~ a
corresponding pixel in response to a gate signal; and
a driving thin film transistor provided in each of the pixels and supplying an electric
current to ~~[[the]]~~ a corresponding electroluminescent element in response to a display signal
supplied through the corresponding pixel selecting thin film transistor,
wherein a carrier mobility of the driving thin film transistor is lower than a carrier
mobility of the pixel selecting thin film transistor.
3. (Original) The electroluminescent display device of claim 2, wherein the pixel
selecting thin film transistor comprises a first polysilicon active layer and the driving thin film
transistor comprises a second polysilicon active layer.

4. (Currently Amended) The electroluminescent display device of claim 3, wherein a [[gain]] grain size of the first polysilicon active layer is larger than a grain size of the second polysilicon active layer.

5-9. (Cancelled).

10. (New) The electroluminescent display device of claim 1, wherein the pixel selecting transistor does not include any amorphous silicon.